

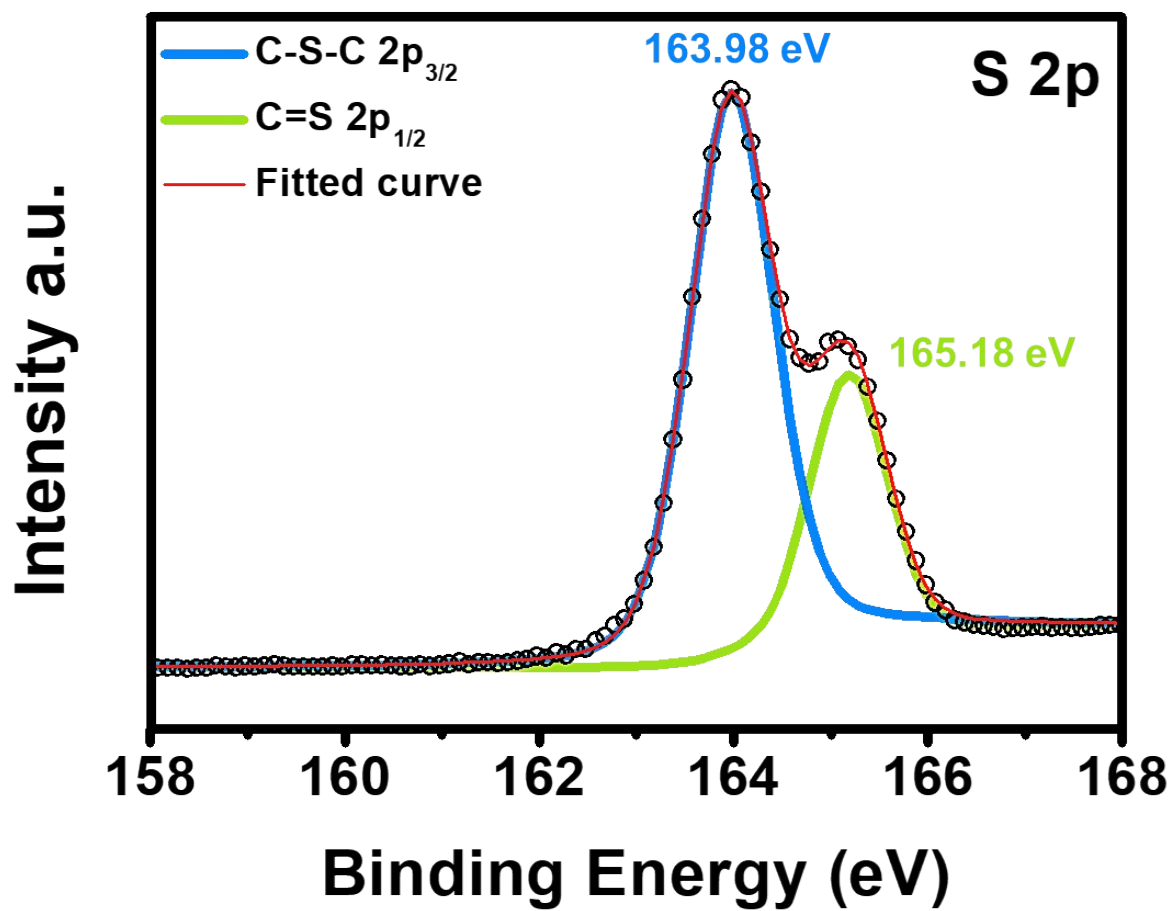
# Long-term cycling stability of SnS<sub>2</sub>-based Covalent Organic Nanosheet anode for Lithium- ion Batteries

*Jeong-Hun Jang,<sup>a</sup> Minseop Lee,<sup>a</sup> Soohyeon Park,<sup>b</sup> Jae-Min Oh,<sup>c\*</sup> Jin Kuen Park<sup>b\*</sup> and  
Seung-Min Paek<sup>a\*</sup>*

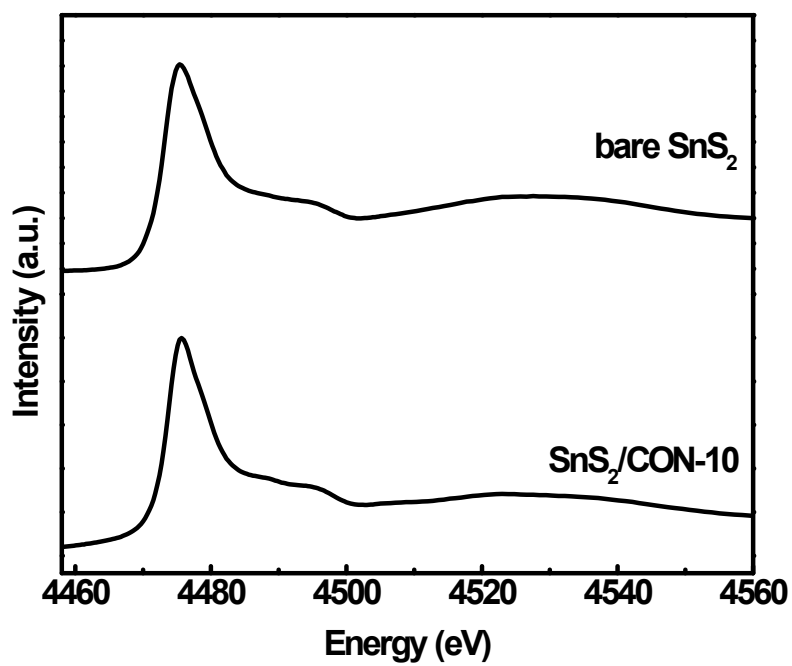
<sup>a</sup>Department of Chemistry, Kyungpook National University, Daegu 41566, Republic of  
Korea E-mail: smpaek@knu.ac.kr

<sup>b</sup>Department of Chemistry, Hankuk University of Foreign Studies, Yongin 17035, Republic  
of Korea, E-mail: jinpark@hufs.ac.kr

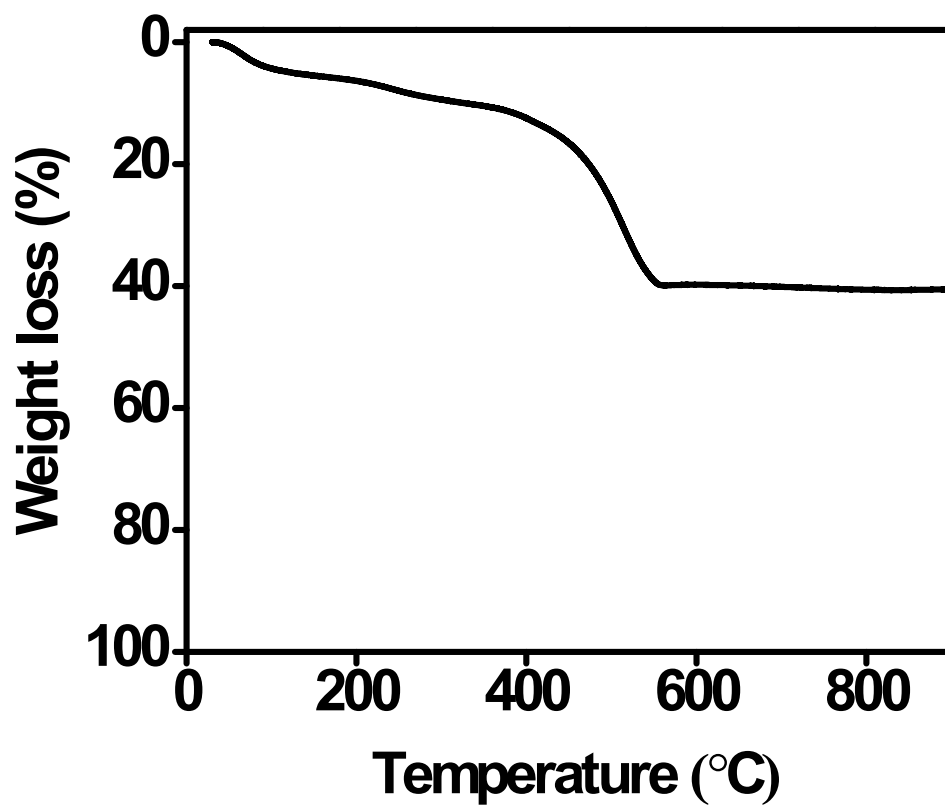
<sup>c</sup>Department of Energy and Materials Engineering, Dongguk University-Seoul, Seoul 04620,  
Republic of Korea. Email: jaemin.oh@dongguk.edu



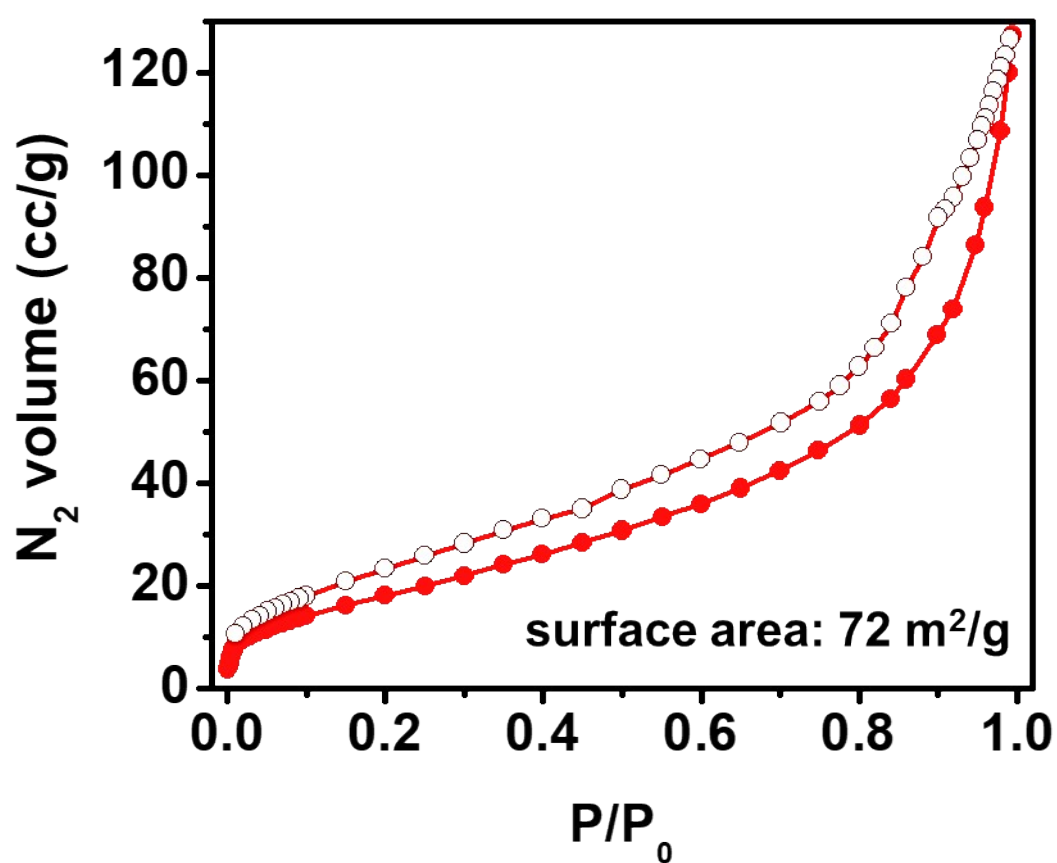
**Figure S1.** High-resolution S 2p XPS spectrum of CON-10.



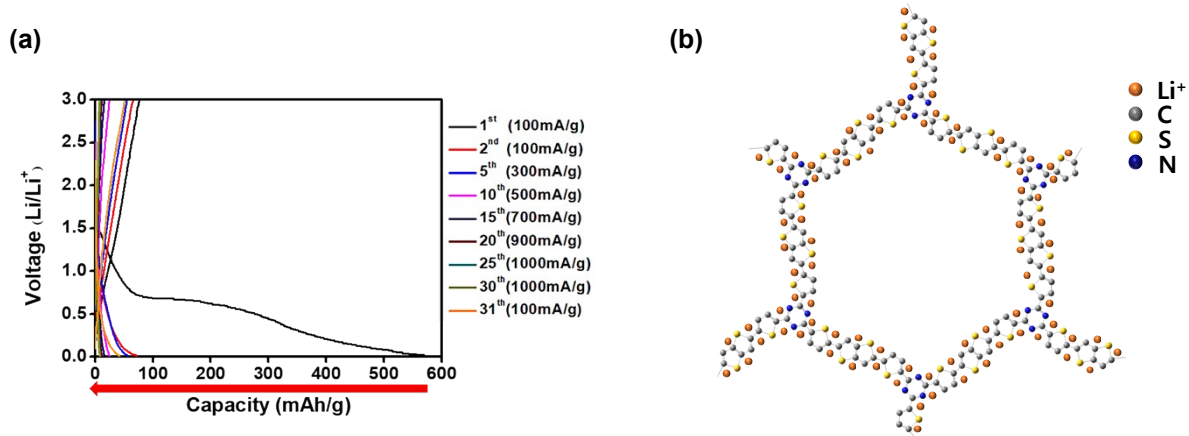
**Figure S2.** X-ray absorption near edge structure (XANES) data for bare SnS<sub>2</sub> and SnS<sub>2</sub>/CON-10.



**Figure S3.** TGA curve of SnS<sub>2</sub>/CON-10.

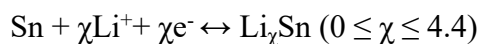
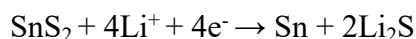


**Figure S4.** N<sub>2</sub> adsorption/desorption isotherm of SnS<sub>2</sub>/CON-10.



**Figure S5.** (a) Charge-discharge profile of CON-10 at 100 mA/g; (b) Schematic redox reaction mechanism of CON-10.

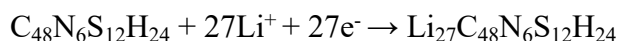
According to the previous literature,<sup>1a</sup> the reaction equation for SnS<sub>2</sub> via two steps (conversion/reconversion and alloying/dealloying) can be written as follows:



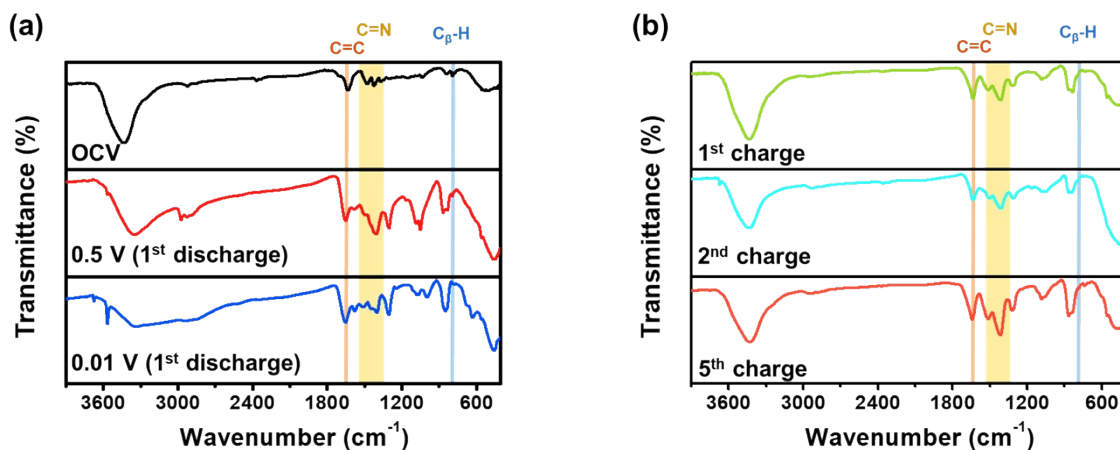
Theoretical Li-ion storage of CON-10 was calculated by Faraday's law equation as follows:

$$\text{Theoretical capacity (mAh/g)} = (n \cdot F) / (3600 \cdot M_w) \cdot 1000$$

Where  $n$  is the number of Li-ion,  $F$  is the Faraday constant (96485.3321 C/mol), and  $M_w$  is the molecular weight of the active materials. The repeating unit of CON-10 consists of two triazine, six thiophene, and three thionothiophene units where redox active sites are located on double-bond groups (C=C and C=N). We estimated that 30 Li<sup>+</sup> ions can be stored at a CON-10 repeating unit as seen in Figure S5(b).<sup>1b</sup> The molecular weight of the CON-10 repeating unit (C<sub>48</sub>N<sub>6</sub>S<sub>12</sub>H<sub>24</sub>) is calculated to be 1070 g/mol. From Faraday's law equation, the theoretical capacity of CON-10 was calculated to be 676 mAh/g, which is in good agreement with the discharge capacity of 1<sup>st</sup> cycle. Therefore the reaction equation for 1<sup>st</sup> cycle can be as follows:

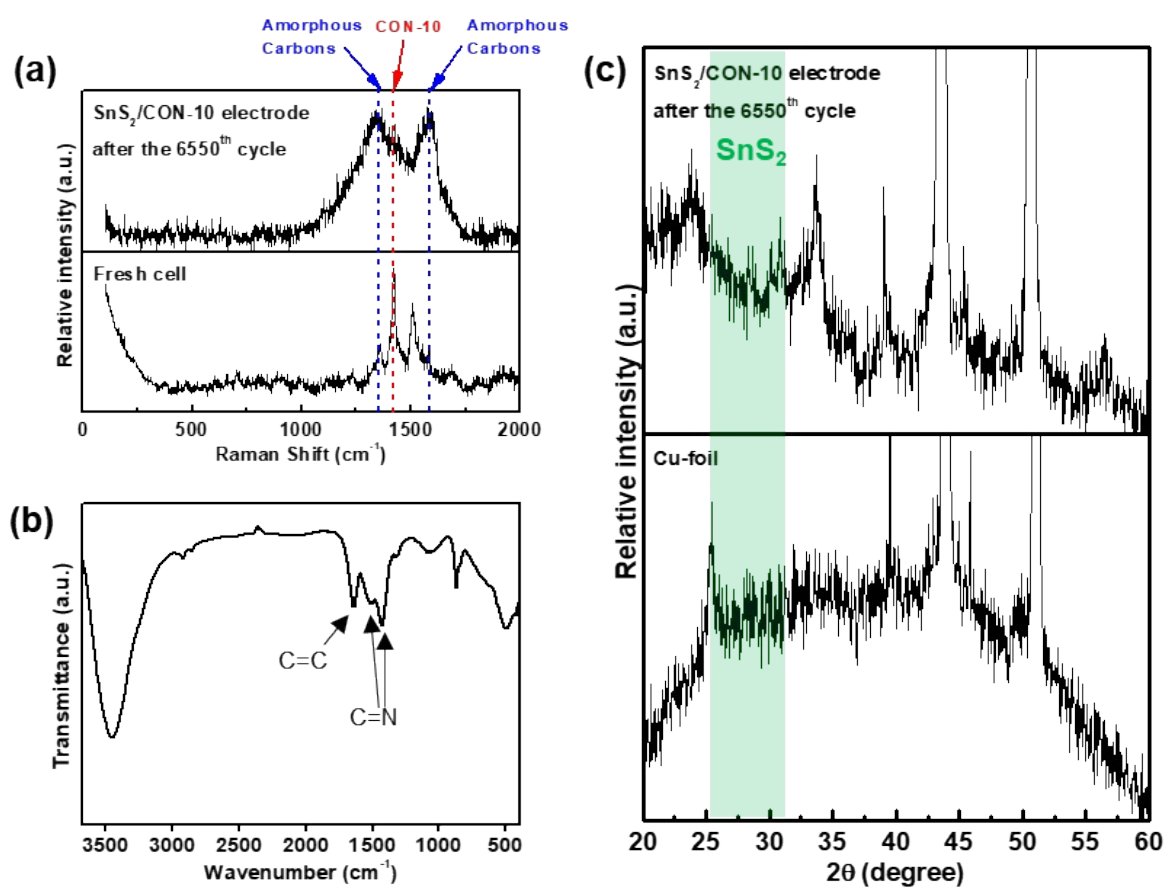


CON-10 loses most of its Li-ion storage capacity due to Li-ions being irreversibly trapped after the first discharge in Li-ion-accessible pores. On the other hand, in SnS<sub>2</sub>/CON-10, SnS<sub>2</sub> generated at the pore part of CON-10 reduces the total pore volume (**Figure S4**).<sup>1c</sup> Therefore, SnS<sub>2</sub>/CON-10 shows excellent capacity retention due to the synergistic effect of SnS<sub>2</sub> located in the pores of CON-10, where Li-ions were irreversibly captured, and CON-10, which prevents pulverization of SnS<sub>2</sub> (**Figure 8**).



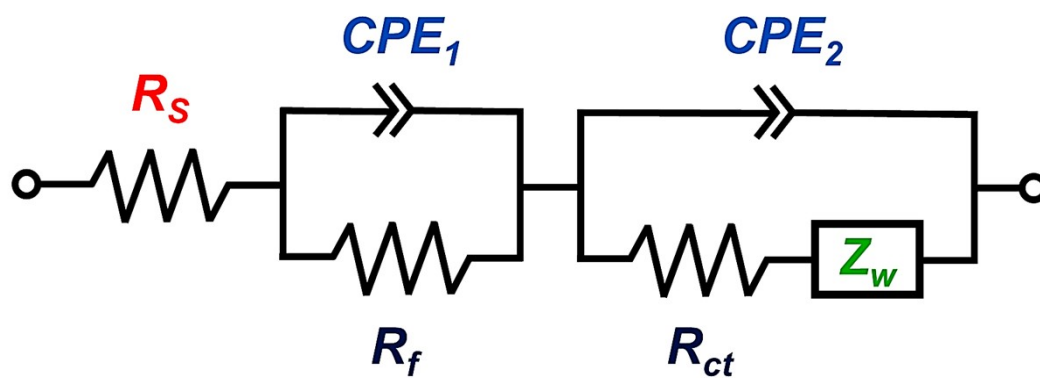
**Figure S6.** Ex-situ FTIR profiles of SnS<sub>2</sub>/CON-10 electrodes upon varying voltages in the initial 5 cycles.

Although some irreversible electrolyte byproduct formation was observed after the 1<sup>st</sup> discharge cycle, the C=C vibration mode and the C=N stretching vibration peak of the CON-10 framework were well observed until the 5<sup>th</sup> cycle. Therefore, by comparing the FTIR profile of CON-10 reported in previous literature, it was confirmed that the structure of CON-10 inside the SnS<sub>2</sub>/CON-10 electrode was well maintained.

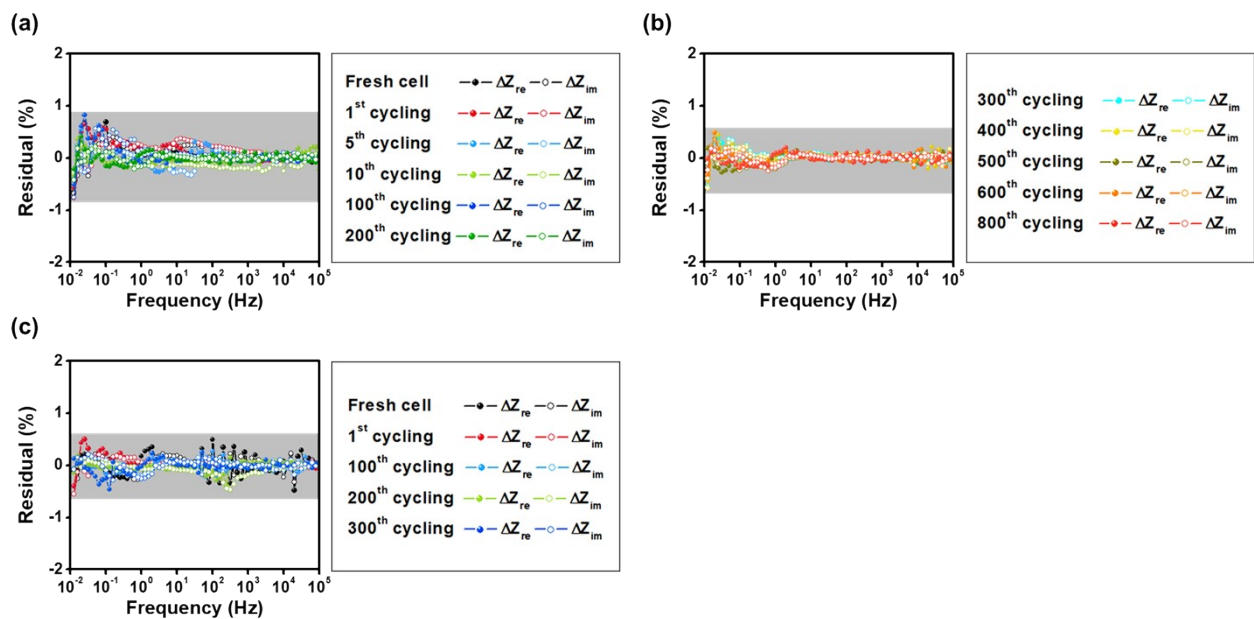


**Figure S7.** (a) Ex-situ FTIR profile, (b) Ex-situ Raman spectrum, and (c) XRD pattern of  $\text{SnS}_2/\text{CON-10}$  electrodes after 6550<sup>th</sup> cycle.





**Figure S8.** The equivalent circuit model for the EIS data fitting.



**Figure S9.** Relative Kramers-Kronig residuals of the (a,b) SnS<sub>2</sub>/CON-10 and (c) as-synthesized SnS<sub>2</sub> electrodes.

**Table S1.** Summary of recent works for the SnS<sub>2</sub>-based carbonaceous anode materials used in lithium ion batteries; <sup>a</sup>capacity (mAh/g); <sup>b</sup>current density (mA/g)

| Anode materials                                   | Capacity<br>(Capacity <sup>a</sup> /Current<br>density <sup>b</sup> /Cycle number) | Voltage<br>range<br>(vs. Li/Li <sup>+</sup> ) | Ref.         |
|---------------------------------------------------|------------------------------------------------------------------------------------|-----------------------------------------------|--------------|
| SnS <sub>2</sub> /rGO-I                           | 215.3/10/200                                                                       | 0.005-3                                       | 2            |
| SnS <sub>2</sub> @GNS                             | 798.6/0.5/100                                                                      | 0.01-3                                        | 3            |
| SnS <sub>2</sub> /NC-5                            | 398.9/0.1/50                                                                       | 0.01-3                                        | 4            |
| SnS <sub>2</sub> /NC@GO                           | 603/0.1/50                                                                         | 0.01-3                                        | 5            |
| hierachical SnS <sub>2</sub> -rGO microsphere     | 1177.2/1/400                                                                       | 0.01-3                                        | 6            |
| PPy@SnS <sub>2</sub> @N3DG                        | 1050/0.5/500                                                                       | 0.01-3                                        | 7            |
| SnS <sub>2</sub> /graphene multilayers            | 160/2/2000                                                                         | 0.02-3                                        | 8            |
| SnS <sub>2</sub> /C-NB                            | 660.2/1/200                                                                        | 0.01-3                                        | 9            |
| SnS <sub>2</sub> /C-rGO                           | 952/0.1/90                                                                         | 0.01-3                                        | 10           |
| SnS <sub>2</sub> -1@rGO                           | 1045.8/0.5/700                                                                     | 0.05-3                                        | 11           |
| SnS <sub>2</sub> @g-C <sub>3</sub> N <sub>4</sub> | 1305.7/0.5/600                                                                     | 0.01-3                                        | 12           |
| SnS <sub>2</sub> /CNTs                            | 660/0.1/100                                                                        | 0.001-3                                       | 13           |
| SnS <sub>2</sub> /C                               | 847.9/0.1/100                                                                      | 0.01-3                                        | 14           |
| SnS <sub>2</sub> -CNT-CC                          | 879/2/200                                                                          | 0.3-3                                         | 15           |
| SnS <sub>2</sub> /S-rGO                           | 1776.4/1/200                                                                       | 0.01-3                                        | 16           |
| SnS <sub>2</sub> QDs/NG                           | 754.2/0.5/1000                                                                     | 0.001-3                                       | 17           |
| D-SnS <sub>2</sub> /PC                            | 596.5/1/1000                                                                       | 1-2.5                                         | 18           |
| SnS <sub>2</sub> @HMCNS                           | 601/1/1000                                                                         | 0.001-3                                       | 19           |
| SnS <sub>2</sub> /rGO heterostructure             | 450/1/1000                                                                         | 0.02-3                                        | 20           |
| SnS <sub>2</sub> /CON-10                          | 917.4/0.3/400<br>514.8/1/3000                                                      | 0.01-3                                        | This<br>work |

**Table S2.** Impedance parameters are fitted through the equivalent circuit model in **Figure S8**.

|                           | SnS <sub>2</sub> /CON-10 |                    |                       |
|---------------------------|--------------------------|--------------------|-----------------------|
|                           | $R_s$ ( $\Omega$ )       | $R_f$ ( $\Omega$ ) | $R_{ct}$ ( $\Omega$ ) |
| Fresh cell                | 26.4                     | -                  | 71.4                  |
| 1 <sup>st</sup> cycling   | 13.9                     | 3.51               | 11.8                  |
| 5 <sup>th</sup> cycling   | 12.7                     | 4.23               | 18.5                  |
| 10 <sup>th</sup> cycling  | 19.7                     | 4.59               | 21.6                  |
| 100 <sup>th</sup> cycling | 20.5                     | 4.62               | 32.8                  |
| 200 <sup>th</sup> cycling | 17.2                     | 4.68               | 35.3                  |
| 300 <sup>th</sup> cycling | 17.0                     | 3.75               | 33.4                  |
| 400 <sup>th</sup> cycling | 7.3                      | 3.59               | 29.8                  |
| 500 <sup>th</sup> cycling | 13.2                     | 3.11               | 24.2                  |
| 600 <sup>th</sup> cycling | 12.9                     | 3.28               | 22.7                  |
| 800 <sup>th</sup> cycling | 13.1                     | 3.22               | 21.0                  |

The equivalent series resistance,  $R_s$ , is related to the ionic conductivity of the electrolyte and the electronic contact resistance associated with the entire cell component. The resistive element in the mid-frequency region (100 kHz to 200 mHz) appears as two resistive elements superimposed and can be identified as the film resistance ( $R_f$ ) and the charge transfer resistance ( $R_{ct}$ ).  $R_f$  is related to the charge transfer resistance in the solid electrolyte interface (SEI) layer and the formation of interfacial electronic contact between the current collector and the active material.  $R_{ct}$  is related to the charge transfer resistance at the interface between the electrolyte and active material.<sup>21-26</sup>

**Table S3.** Impedance parameters are fitted through the equivalent circuit model in **Figure S8**.

|                           | as-synthesized SnS <sub>2</sub> |                    |                       |
|---------------------------|---------------------------------|--------------------|-----------------------|
|                           | $R_s$ ( $\Omega$ )              | $R_f$ ( $\Omega$ ) | $R_{ct}$ ( $\Omega$ ) |
| Fresh cell                | 5.64                            | -                  | 50.1                  |
| 1 <sup>st</sup> cycling   | 7.2                             | 7.32               | 10.2                  |
| 100 <sup>th</sup> cycling | 35.3                            | 7.13               | 77.5                  |
| 200 <sup>th</sup> cycling | 35.5                            | 7.15               | 85.1                  |
| 300 <sup>th</sup> cycling | 14.3                            | 7.12               | 100.7                 |

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